

2SK2373

Silicon N Channel MOS FET

REJ03G1009-0300 Rev.3.00 Dec 27, 2006

Application

High speed power switching

Features

- Low on-resistance
- Small package
- Low drive current
- 4 V gate drive device can be driven from 5 V source.
- Suitable for low signal load switch

Outline

RENESAS Package code: PLSP0003ZB-A (Package name: MPAK)

1. Source
2. Gate
3. Drain

Note: Marking is "ZE-".

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	0.2	А
Drain peak current	I _{D(pulse)} *1	0.4	А
Body to drain diode reverse drain current	I _{DR}	0.2	А
Channel dissipation	Pch*2	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. PW \leq 100 μ s, duty cycle \leq 10 %

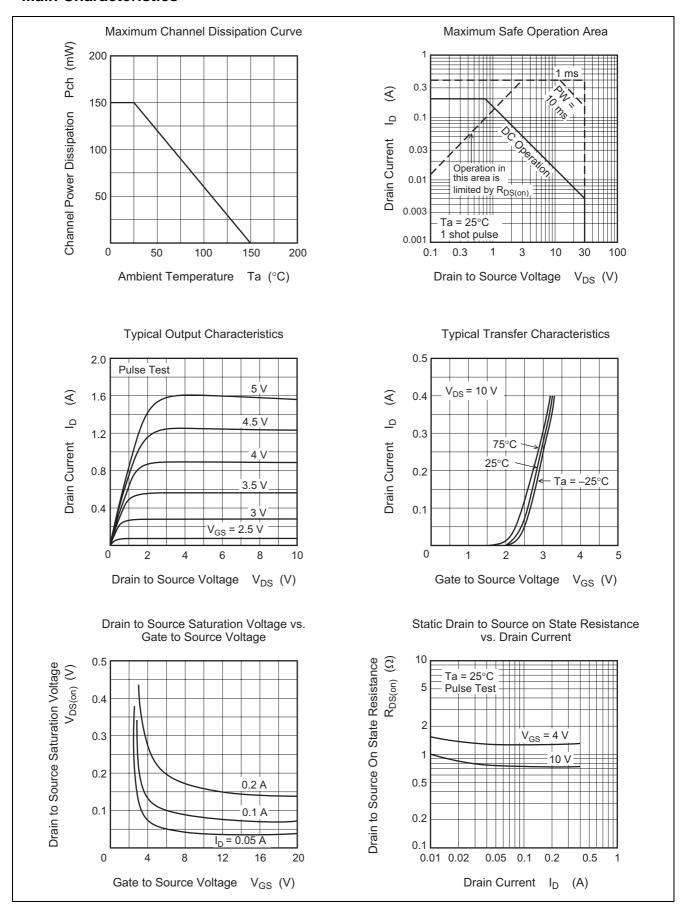
Electrical Characteristics

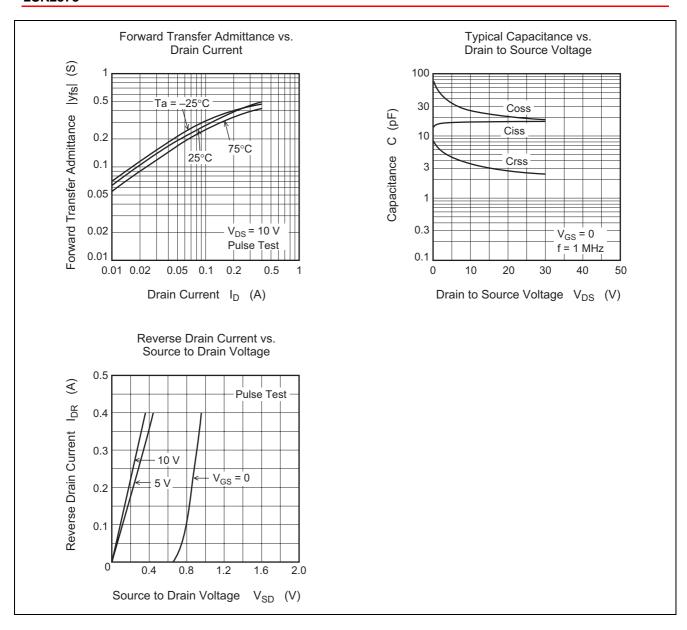
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 100 \mu A, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I_{GSS}	_	_	±2	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.0	V	$I_D = 10 \mu A, V_{DS} = 5 V$
Static drain to source on state	R _{DS(on)}	_	1.4	7.5	Ω	$I_D = 20 \text{ mA}, V_{GS} = 4 \text{ V}^{*2}$
resistance		_	1.0	7.0	Ω	$I_D = 10 \text{ mA}, V_{GS} = 10 \text{ V}^{*2}$
Input capacitance	Ciss	_	17.8	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	25.4	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	3.7	_	pF	
Turn-on delay time	t _{d(on)}	_	50	_	ns	$I_D = 0.1 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time	t _r	_	125	_	ns	$R_L = 100 \Omega$, PW = 2 μ s
Turn-off delay time	$t_{d(off)}$	_	660	_	ns	
Fall time	t _f	_	400	_	ns	

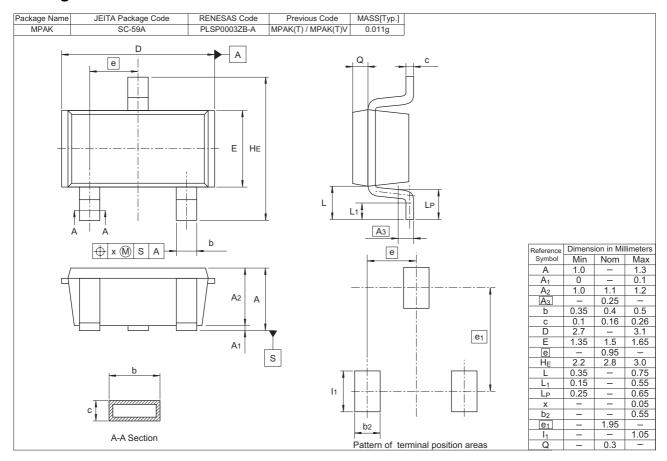
Note: 2. Pulse Test

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK2373ZE-TL-E	3000 pcs	Taping
2SK2373ZE-TR-E	3000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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